

## 1 Amp. Glass Passivated Ultrafast Recovery Rectifier

<p><b>Dimensions in mm.</b></p> <p><b>DO-41 (Plastic)</b></p>	<p><b>Voltage</b> 50 to 1000 V.</p> <p><b>Current</b> 1 A at 55 °C.</p> <p></p>
<p><b>Mounting instructions</b></p> <ol style="list-style-type: none"> <li>Min. distance from body to soldering point, 4 mm.</li> <li>Max. solder temperature, 350 °C.</li> <li>Max. soldering time, 3.5 sec.</li> <li>Do not bend lead at a point closer than 2 mm. to the body.</li> </ol> <ul style="list-style-type: none"> <li>• <b>Glass Passivated Junction</b></li> <li>• High current capability</li> <li>• The plastic material carries U/L recognition 94 V-0</li> <li>• Terminals: Axial Leads</li> <li>• Polarity: Color band denotes cathode</li> </ul>	

### Maximum Ratings, according to IEC publication No. 134

		FUF 4001	FUF 4002	FUF 4003	FUF 4004	FUF 4005	FUF 4006	FUF 4007
$V_{RRM}$	Peak Recurrent reverse voltage (V)	50	100	200	400	600	800	1000
$V_{RMS}$	Maximum RMS voltage	35	70	140	280	420	560	700
$V_{DC}$	Maximum DC blocking voltage	50	100	200	400	600	800	1000
$I_{F(AV)}$	Forward current at $T_{amb} = 55^\circ C$							1 A
$I_{FRM}$	Recurrent peak forward surge current							10 A
$I_{FSM}$	8.3 ms. peak forward surge current (Jedec Method)							30 A
$t_{rr}$	Max. reverse recovery time from $I_F = 0.5 A$ ; $I_R = 1 A$ ; $I_{RR} = 0.25 A$			50 ns				75 ns
$C_j$	Typical Junction Capacitance at 1 MHz and reverse voltage of $4V_{DC}$					15 pF		
$T_j$	Operating temperature range				– 65 to + 150 °C			
$T_{stg}$	Storage temperature range				– 65 to + 150 °C			
$E_{RSM}$	Maximum non repetitive peak reverse avalanche energy. $I_R = 0.5 A$ ; $T_j = 25^\circ C$					20 mJ		

### Electrical Characteristics at $T_{amb} = 25^\circ C$

$V_F$	Max. forward voltage drop at $I_F = 1 A$	1.3 V	1.7 V
$I_R$	Max. reverse current at $V_{RRM}$ at $25^\circ C$	5 $\mu A$	
$R_{thj-a}$	Max. thermal resistance ( $l = 10 \text{ mm.}$ )		50 °C/W

## Rating And Characteristic Curves

